



Characterizing the phase purity of nanocrystalline Fe₃O₄ thin films using Verwey transition



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ABSTRACT

We have employed Verwey transition as a probe to check phase purity of nanocrystalline Fe₃O₄ films grown at different substrate temperatures (T_s) by means of magnetization study. The drop in magnetization at temperatures other than Verwey transition temperature T_v (120 K), in the low and high T_s films indicates the presence of antiferromagnetic (α -Fe₂O₃/FeO) impurity phases. After wet H₂ reduction treatment on these films, a vibrant appearance of Verwey transition is observed which confirms Fe₃O₄ phase at all T_s . However, high T_s films exhibit low T_v value with distribution, $T_v \pm \Delta T_v = 112 \pm 25$ K emanating from residual magnetic phases, which were not traced by XRD studies. Interestingly, these nanocrystalline Fe₃O₄ films exhibit anisotropic magnetic behaviors above T_v , similar to the single crystal Fe₃O₄. Below the saturation field, the easy (111) and relatively hard (110) axis of magnetizations align along their texture planes.

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1. Introduction

Considering the recently demonstrated novel spintronic applications of nanosize Fe₃O₄ films [1–4], ranging from sensors based on the high magneto-resistance ratio change at Verwey transition [2] to the ultrafast switches wherein electric field driven Verwey transition is exploited [3–4], it is imperative to study Verwey transition of Fe₃O₄ films at nanoscale. The fingerprint of stoichiometric Fe₃O₄ single crystal is Verwey transition [5] at 120 K (T_v), wherein the resistivity abruptly increases by two orders of magnitude caused by structural transformation from high symmetric cubic phase to low symmetric monoclinic Fe₃O₄ phase. The consequence of this transition also influences the magnetic properties below the saturation magnetic field [5–9]. In the vicinity of Verwey transition at 130 K, the first-order magneto-crystalline anisotropy constant (K_1) of Fe₃O₄ also happens to change its sign [8–9]. However, the appearance of Verwey transition in the magnetic properties is more robust [10–12] compared to the electrical transport, wherein presence of smaller grain sizes, grain boundary volume and slight crystalline disorders/defects in nanocrystalline Fe₃O₄ could easily mask this transition [1–2,10–12]. Besides, the

growth of Fe₃O₄ films by non-equilibrium processes like gas phase synthesis methods often produce many secondary insulating phases [α -Fe₂O₃ (antiferromagnetic), FeO (antiferromagnetic) and γ -Fe₂O₃ (ferrimagnetic)], drastically affecting the Verwey transition [13]. Therefore, growth of single phase Fe₃O₄ presents a significant challenge to researchers and hence alternative growth and characterization approaches need to be explored. Whilst x-ray diffraction and high resolution transmission electron microscopy have been the most powerful techniques to study bulk vs. interface properties in terms of their lattices, it is generally difficult to identify isostructural compounds (viz. Fe₃O₄, γ -Fe₂O₃ and FeO all three exhibit cubic structure) from these techniques.

In the present study, we employed Verwey transition as a novel way to check phase purity of nanocrystalline Fe₃O₄ films grown at various substrate temperature followed by wet H₂ reduction treatment through magnetic measurements.

2. Experimental

Thin films (~800 nm) were grown by pulsed laser ablation of α -Fe₂O₃ target on amorphous fused quartz substrates in vacuum of 1×10^{-5} mbar [14]. The substrate temperature (T_s) was varied from room temperature (RT) to 850 °C. After deposition, these films were reduced under wet H₂ environment in order to get single phase Fe₃O₄ as follows: the films were first introduced into

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